NSN 5962-01-116-5779

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View Online at https://aerobasegroup.com/nsn/5962-01-116-5779 **Body Length:** Between 0.880 inches and 0.920 inches **Body Width:** Between 0.280 inches and 0.305 inches **Body Height:** 0.140 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** 6930-01-102-2345 36378 **Features Provided:** Hermetically sealed and high speed and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 15 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Memory Capacity:** Unknown **Terminal Type And Quantity:** 18 printed circuit Shelf Life:

Demilitarization:

Unit Of Measure:

Yes - demil/mli

N/a

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